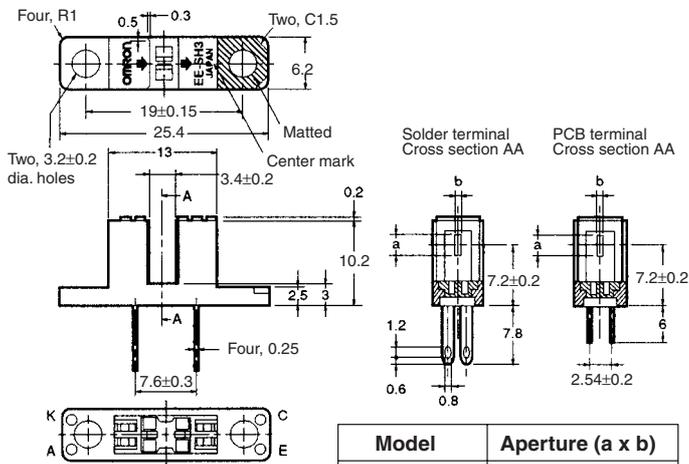


## Photomicrosensor (Transmissive) EE-SH3 Series

**⚠ Be sure to read *Precautions* on page 25.**

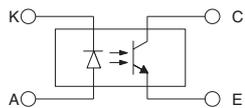
### ■ Dimensions

**Note:** All units are in millimeters unless otherwise indicated.



| Model       | Aperture (a x b) |
|-------------|------------------|
| EE-SH3(-B)  | 2.1 x 0.5        |
| EE-SH3-C(S) | 2.1 x 1.0        |
| EE-SH3-D(S) | 2.1 x 0.2        |
| EE-SH3-G(S) | 0.5 x 2.1        |

### Internal Circuit



Unless otherwise specified, the tolerances are as shown below.

| Dimensions   | Tolerance |
|--------------|-----------|
| 3 mm max.    | ±0.2      |
| 3 < mm ≤ 6   | ±0.24     |
| 6 < mm ≤ 10  | ±0.29     |
| 10 < mm ≤ 18 | ±0.35     |
| 18 < mm ≤ 30 | ±0.42     |

| Terminal No. | Name      |
|--------------|-----------|
| A            | Anode     |
| K            | Cathode   |
| C            | Collector |
| E            | Emitter   |

### ■ Features

- High-resolution model with a 0.2-mm-wide or 0.5-mm-wide sensing aperture, high-sensitivity model with a 1-mm-wide sensing aperture, and model with a horizontal sensing aperture are available.
- Solder terminal models:  
EE-SH3/-SH3-CS/-SH3-DS/-SH3-GS
- PCB terminal models:  
EE-SH3-B/-SH3-C/-SH3-D/-SH3-G

### ■ Absolute Maximum Ratings (Ta = 25°C)

| Item                  | Symbol                    | Rated value               |
|-----------------------|---------------------------|---------------------------|
| Emitter               | Forward current           | $I_F$ 50 mA (see note 1)  |
|                       | Pulse forward current     | $I_{FP}$ 1 A (see note 2) |
|                       | Reverse voltage           | $V_R$ 4 V                 |
| Detector              | Collector–Emitter voltage | $V_{CEO}$ 30 V            |
|                       | Emitter–Collector voltage | $V_{ECO}$ ---             |
|                       | Collector current         | $I_C$ 20 mA               |
|                       | Collector dissipation     | $P_C$ 100 mW (see note 1) |
| Ambient temperature   | Operating                 | $T_{opr}$ -25°C to 85°C   |
|                       | Storage                   | $T_{stg}$ -30°C to 100°C  |
| Soldering temperature | $T_{sol}$                 | 260°C (see note 3)        |

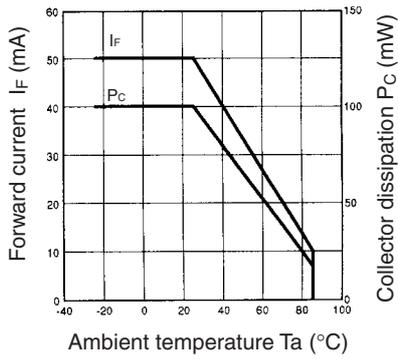
- Note:**
- Refer to the temperature rating chart if the ambient temperature exceeds 25°C.
  - The pulse width is 10 μs maximum with a frequency of 100 Hz.
  - Complete soldering within 10 seconds.

### ■ Electrical and Optical Characteristics (Ta = 25°C)

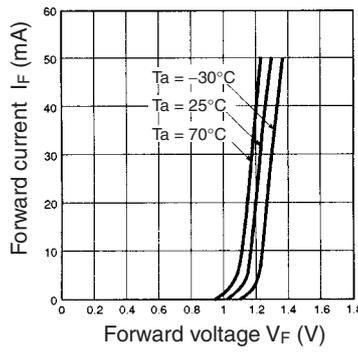
| Item         | Symbol                               | Value                |                          |                 |             | Condition   |                                   |
|--------------|--------------------------------------|----------------------|--------------------------|-----------------|-------------|---|-----------------------------------|
|              |                                      | EE-SH3(-B)           | EE-SH3-C(S)              | EE-SH3-D(S)     | EE-SH3-G(S) |   |                                   |
| Emitter      | Forward voltage                      | $V_F$                | 1.2 V typ., 1.5 V max.   |                 |             | $I_F = 30$ mA                                     |                                   |
|              | Reverse current                      | $I_R$                | 0.01 μA typ., 10 μA max. |                 |             | $V_R = 4$ V                                       |                                   |
|              | Peak emission wavelength             | $\lambda_p$          | 940 nm typ.              |                 |             | $I_F = 20$ mA                                     |                                   |
| Detector     | Light current                        | $I_L$                | 0.5 to 14 mA typ.        | 1 to 28 mA typ. | 0.1 mA min. | 0.5 to 14 mA                                      | $I_F = 20$ mA,<br>$V_{CE} = 10$ V |
|              | Dark current                         | $I_D$                | 2 nA typ., 200 nA max.   |                 |             | $V_{CE} = 10$ V,<br>0 lx                          |                                   |
|              | Leakage current                      | $I_{LEAK}$           | ---                      |                 |             | ---   |                                   |
|              | Collector–Emitter saturated voltage  | $V_{CE}(\text{sat})$ | 0.1 V typ., 0.4 V max.   |                 | ---         | 0.1 V typ.,<br>0.4 V max.                         | $I_F = 20$ mA,<br>$I_L = 0.1$ mA  |
|              | Peak spectral sensitivity wavelength | $\lambda_p$          | 850 nm typ.              |                 |             | $V_{CE} = 10$ V                                   |                                   |
| Rising time  | $t_r$                                | 4 μs typ.            |                          |                 |             | $V_{CC} = 5$ V,<br>$R_L = 100$ Ω,<br>$I_L = 5$ mA |                                   |
| Falling time | $t_f$                                | 4 μs typ.            |                          |                 |             |   |                                   |

■ Engineering Data

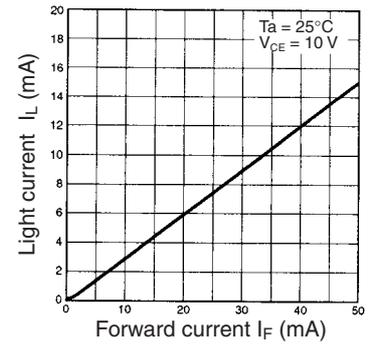
Forward Current vs. Collector Dissipation Temperature Rating



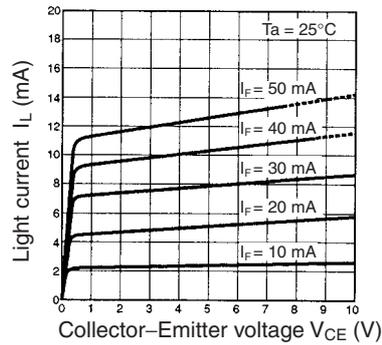
Forward Current vs. Forward Voltage Characteristics (Typical)



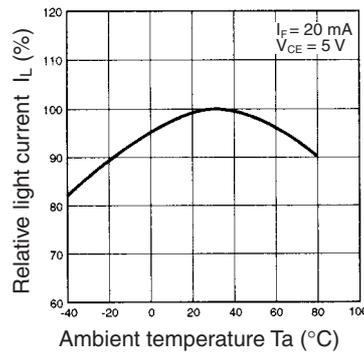
Light Current vs. Forward Current Characteristics (Typical)



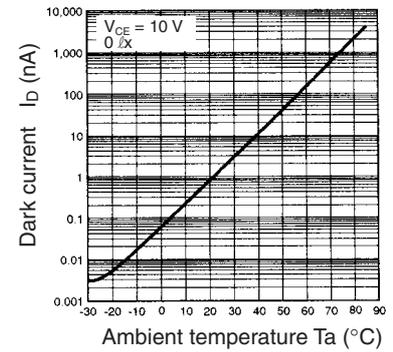
Light Current vs. Collector-Emitter Voltage Characteristics (EE-SH3(-B))



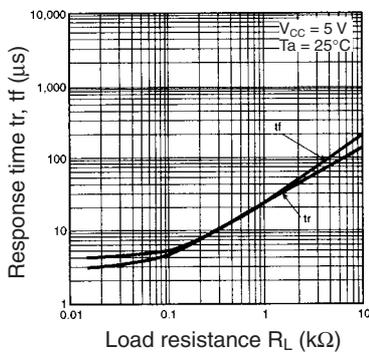
Relative Light Current vs. Ambient Temperature Characteristics (Typical)



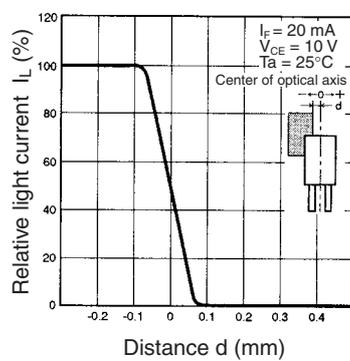
Dark Current vs. Ambient Temperature Characteristics (Typical)



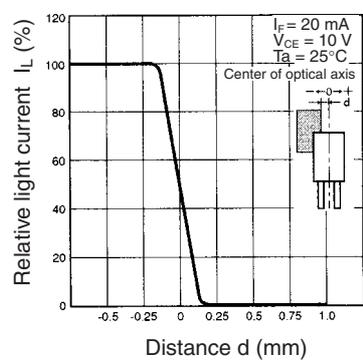
Response Time vs. Load Resistance Characteristics (Typical)



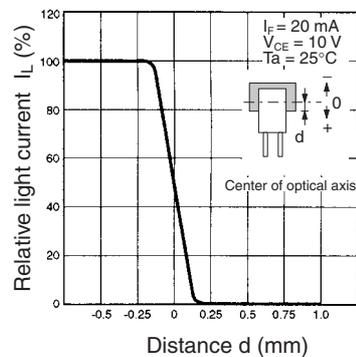
Sensing Position Characteristics (EE-SH3-D(S))



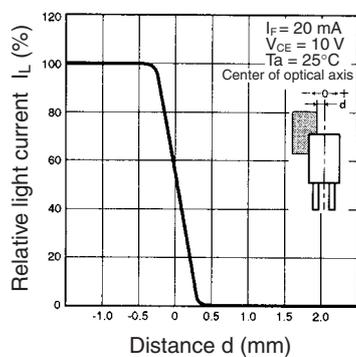
Sensing Position Characteristics (EE-SH3(-B))



Sensing Position Characteristics (EE-SH3-G(S))



Sensing Position Characteristics (EE-SH3-C(S))



Response Time Measurement Circuit

